









LMV358, LMV321, LMV324, LMV324S SLOS263Y - AUGUST 1999 - REVISED AUGUST 2023

LMV3xx Low-Voltage Rail-to-Rail Output Operational Amplifier

1 Features

- For an upgraded version refer to LMV321A, LMV358A, and LMV324A
- 2.7-V and 5-V performance
- -40°C to +125°C operation
- No crossover distortion
- Low supply current
 - LMV321: 130 µA (typical)
 - LMV358: 210 μA (typical)
 - LMV324: 410 µA (typical)
- Rail-to-rail output swing
- ESD protection exceeds JESD 22
 - 2000-V human-body model
 - 1000-V charged-device model

2 Applications

- **Desktop PCs**
- HVAC: heating, ventilating, and air conditioning
- Motor control: AC induction
- **Net-books**
- Portable media players
- Power: telecom DC/DC module: digital
- Professional audio mixers
- Refrigerators
- Washing machines: high-end and low-end

3 Description

For an upgraded version with enhanced performance, please refer to LMV321A, LMV358A, and LMV324A.

The LMV321, LMV358, and LMV324 devices are single, dual, and quad low-voltage (2.7 V to 5.5 V) operational amplifiers with rail-to-rail output swing. These devices are the most cost-effective solutions for applications where low-voltage operation, space saving, and low cost are needed. These amplifiers are designed specifically for low-voltage (2.7 V to 5 V) operation, with performance specifications meeting or exceeding the LM358 and LM324 devices that operate from 5 V to 30 V. With package sizes down to one-half the size of the DBV (SOT-23) package, these devices can be used for a variety of applications.

Device Information

PART NUMBER	CHANNEL COUNT	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)					
LMV321	Single	DBV (SOT-23, 5)	2.90 mm × 2.80 mm					
LIVIV 32 I	Sirigle	DCK (SC-70, 5)	2.00 mm × 2.10 mm					
	Dual	D (SOIC, 8)	4.90 mm × 6.00 mm					
LMV358		DDU (VSSOP, 8)	2.00 mm × 3.10 mm					
LIVIVSSO		DGK (VSSOP, 8)	3.00 mm × 4.90 mm					
		PW (TSSOP, 8)	3.00 mm × 6.40 mm					
LMV324	Quad	D (SOIC, 14)	8.65 mm × 6.00 mm					
LIVI V 324		PW (TSSOP, 14)	5.00 mm × 6.40 mm					

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable.

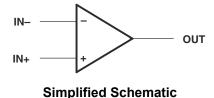




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5 Pin Configuration and Functions

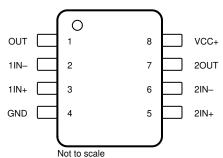


Figure 5-1. D, DDU, DGK, and PW Packages, 8-Pin SOIC, VSSOP, and TSSOP (Top View)

Table 5-1. Pin Functions: LMV358

	PIN	TYPE(1)	DESCRIPTION		
NAME	NO.	ITPE	DESCRIPTION		
1IN+	3	ı	Noninverting input		
1IN-	2	I	Inverting input		
2IN+	5	I	Noninverting input		
2IN-	6	I	Inverting input		
2OUT	7	0	Output		
GND	4	_	Negative supply		
OUT	1	0	Output		
VCC+	8	_	Positive supply		

(1) I = input, O = output

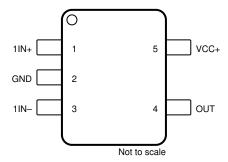


Figure 5-2. DBV and DCK Packages, 5-Pin SOT-23 and SC-70 (Top View)

Table 5-2. Pin Functions: LMV321

PIN		TYPE ⁽¹⁾	DESCRIPTION		
NAME	NO.	IIFE\/	DESCRIP HON		
1IN+	1	I	Noninverting input		
1IN-	3	I	Inverting input		
GND	2	_	Negative supply		
OUT	4	0	Output		
VCC+	5	_	Positive supply		

(1) I = input, O = output



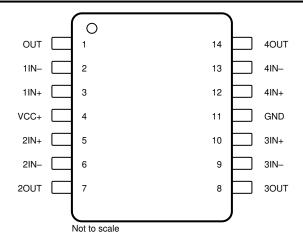


Figure 5-3. D and PW Packages, 14-Pin SOIC and TSSOP (Top View)

Table 5-3. Pin Functions: LMV324

	PIN		DECORIDATION
NAME	NO.	TYPE ⁽¹⁾	DESCRIPTION
3/4 SHDN	_	I	Shutdown (logic low) / enable (logic high)
1/2 SHDN	_	I	Shutdown (logic low) / enable (logic high)
1IN+	3	I	Noninverting input
1IN-	2	I	Inverting input
2IN+	5	I	Noninverting input
2IN-	6	I	Inverting input
2OUT	7	0	Output
3IN+	10	I	Noninverting input
3IN-	9	I	Inverting input
3OUT	8	0	Output
4IN+	12	I	Noninverting input
4IN-	13	I	Inverting input
4OUT	14	0	Output
GND	11	_	Negative supply
OUT	1	0	OUT
VCC+	4	_	Positive supply

(1) I = input, O = output



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽²⁾			5.5	V
V _{ID}	Differential input voltage ⁽³⁾	·		±5.5	V
VI	Input voltage range (either input)	Input voltage range (either input)			V
	Duration of output short circuit (one amplifier) to ground ⁽⁴⁾	At or below T _A = 25°C, V _{CC} ≤ 5.5 V	U	nlimited	
TJ	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.

6.2 ESD Ratings

			MIN	MAX	UNIT
V Clastroctatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	0	2000	V	
V (ESD)	V _(ESD) Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	0	1000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

			MIN	MAX	UNIT
V _{CC}	Supply voltage (single-supply operation)		2.7	5.5	V
T _A	Operating free-air temperature	I temperature (LMV321, LMV358, LMV324, LMV321IDCK)	-40	125	°C
		Q temperature	-40	125	

6.4 Thermal Information: LMV321

		LMV		
THERMAL METRIC ⁽¹⁾		DBV (SOT-23) DCK (SC-70) U		UNIT
		5 PINS	5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	232.9	239.6	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Thermal Information: LMV324

		LMV		
THERMAL METRIC ⁽¹⁾		D (SOIC) PW (TSSOP) U		UNIT
			14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	102.1	148.3	°C/W

For more information about traditional and new thermal metrics, see the <u>Semiconductor and IC Package Thermal Metrics</u> application report.



6.6 Thermal Information: LMV358

		LMV358				
THERMAL METRIC(1)		D (SOIC) DGK (VSSOP) DDU (VSSOP)		PW (TSSOP)	UNIT	
		8 PINS	8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	207.9	201.2	210	200.7	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.7 Electrical Characteristics: V_{CC}+ = 2.7 V

 $V_{CC+} = 2.7 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (unless otherwise noted)}$

	PARAMETER	TEST CONDI	TIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IO}	Input offset voltage				1.7	7	mV
α_{VIO}	Average temperature coefficient of input offset voltage				5		μV/°C
I _{IB}	Input bias current				11	250	nA
I _{IO}	Input offset current				5	50	nA
CMRR	Common-mode rejection ratio	V _{CM} = 0 to 1.7 V		50	63		dB
k _{SVR}	Supply-voltage rejection ratio	V _{CC} = 2.7 V to 5 V, V _O = 1 V		50	60		dB
V	Common mode input valtage range	CMRR ≥ 50 dB		0	-0.2		V
V _{ICR} Com	Common-mode input voltage range				1.9	1.7	
\/	Out out out in	D 40104 4051/	High level	V _{CC} – 100	V _{CC} – 10	180 m\	m\/
Vo	Output swing	$R_L = 10 \text{ k}\Omega \text{ to } 1.35 \text{ V}$	Low level		60		IIIV
		LMV321I	·		80	170	
Icc	Supply current	LMV358I (both amplifiers)			140) 340 µA	
		LMV324I (all four amplifiers)		260	260	680	
B ₁	Unity-gain bandwidth	C _L = 200 pF			1		MHz
Φ _m	Phase margin				60		deg
G _m	Gain margin				10		dB
V _n	Equivalent input noise voltage	f = 1 kHz			46		nV/√ Hz
In	Equivalent input noise current	f = 1 kHz			0.17		pA/√ Hz

⁽¹⁾ Typical values represent the likely parametric nominal values determined at the time of characterization. Typical values depend on the application and configuration and may vary over time. Typical values are not ensured on production material.



6.8 Electrical Characteristics: V_{CC}+ = 5 V

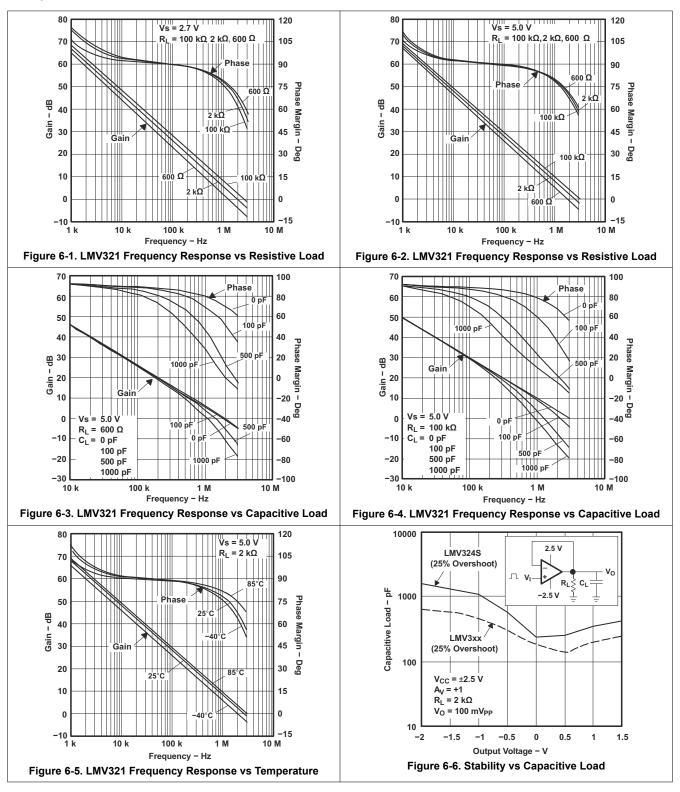
V_{CC+} = 5 V, at specified free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
.,	l	T _A = 25°C		1.7	7	
V _{IO}	Input offset voltage	T _A = -40°C to +125°C			9	mV
α _{VIO}	Average temperature coefficient of input offset voltage	T _A = 25°C		5		μV/°C
ı	Input bigg gurrent	T _A = 25°C		15	250 ⁽¹⁾	n ^
IB	Input bias current	T _A = -40°C to +125°C			500 ⁽¹⁾	nA
l. ₋	Input offset current	T _A = 25°C		5	50 ⁽¹⁾	nA
I _{IO}	input onset current	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$			150 ⁽¹⁾	ПА
CMRR	Common-mode rejection ratio	V _{CM} = 0 to 4 V T _A = 25°C	50	65		dB
k _{SVR}	Supply-voltage rejection ratio	V_{CC} = 2.7 V to 5 V, V_{O} = 1 V, V_{CM} = 1 V T_{A} = 25°C	50	60		dB
V _{ICR}	Common-mode input	CMRR ≥ 50 dB, T _A = 25°C	0	-0.2		V
VICR	voltage range	CWINT 2 30 dB, 1A = 23 C		4.2	4	V
		R_L = 2 k Ω to 2.5 V, high level, T_A = 25°C	V _{CC} - 300	$V_{CC}-40$		
	Output swing	R_L = 2 k Ω to 2.5 V, high level, T_A = -40°C to +125°C	V _{CC} - 400 ⁽¹⁾			
		T _A = 25°C, low level				
Vo		$T_A = -40$ °C to +125°C, low level			400(1)	mV
	Output swing	R_L = 10 kΩ to 2.5 V, high level, T_A = 25°C	V _{CC} – 100	V _{CC} – 10		IIIV
		R_L = 10 k Ω to 2.5 V, high level, T_A = -40°C to +125°C	V _{CC} - 200 ⁽¹⁾			
		T _A = 25°C, low level		65	180	
		$T_A = -40$ °C to +125°C, low level			280(1)	
٨	Large-signal differential	$R_L = 2 k\Omega, T_A = 25^{\circ}C$	15	100		V/mV
A_{VD}	voltage gain	$R_L = 2 \text{ k}\Omega$, $T_A = -40^{\circ}\text{C}$ to +125°C	10 ⁽¹⁾			V/IIIV
ı	Output short-circuit	Sourcing, V _O = 0 V, T _A = 25°C	5 ⁽¹⁾	40		mΛ
los	current	Sinking, V _O = 5 V, T _A = 25°C	10 ⁽¹⁾	40		mA
		LMV321I, T _A = 25°C		130	250	
		LMV321I, $T_A = -40^{\circ}\text{C}$ to +125°C			350	
		LMV358I (both amplifiers), T _A = 25°C		210	440	
I _{cc}	Supply current	LMV358I (both amplifiers), T _A = -40°C to +125°C			615	μΑ
		LMV324I (all four amplifiers), T _A = 25°C		410	830	
		LMV324I (all four amplifiers), T _A = -40°C to +125°C			1160	
B ₁	Unity-gain bandwidth	C _L = 200 pF, T _A = 25°C		1		MHz
Φ _m	Phase margin	T _A = 25°C		60		deg
G _m	Gain margin	T _A = 25°C		10		dB
V _n	Equivalent input noise voltage	f = 1 kHz, T _A = 25°C		39		nV/√ Hz
l _n	Equivalent input noise current	f = 1 kHz, T _A = 25°C		0.21		pA/√ Hz
SR	Slew rate	T _A = 25°C		1		V/µs

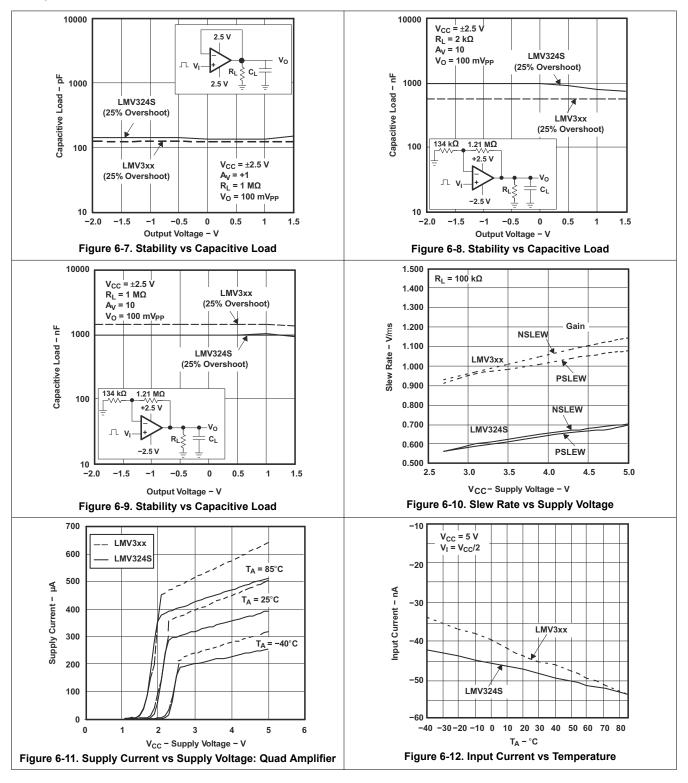
⁽¹⁾ Specified by characterization. Not production tested.



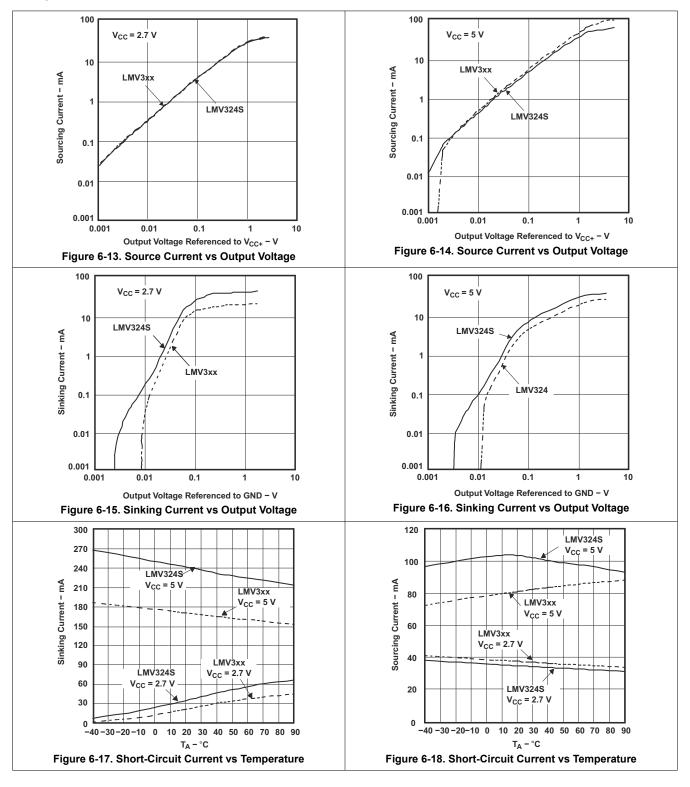
6.9 Typical Characteristics



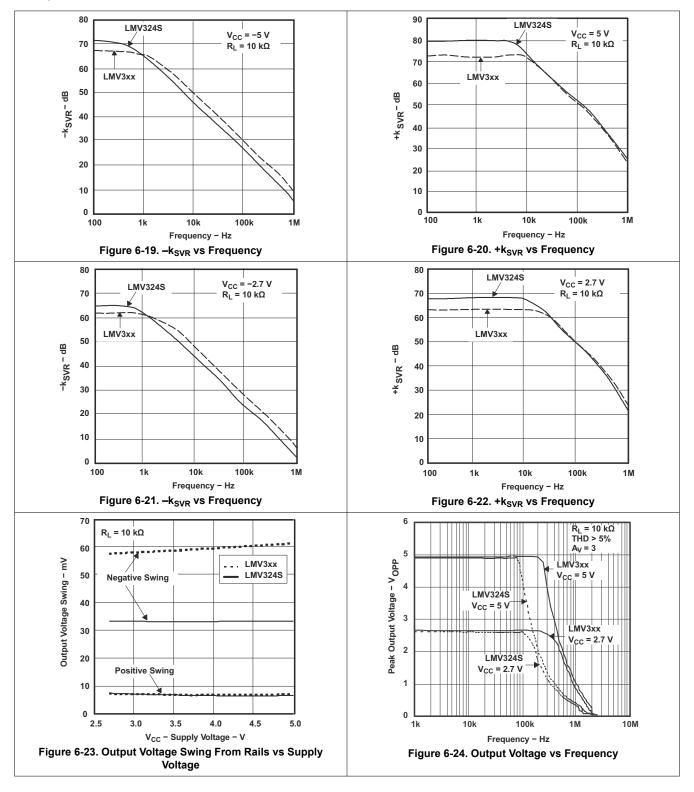




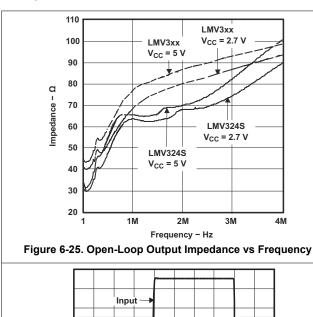












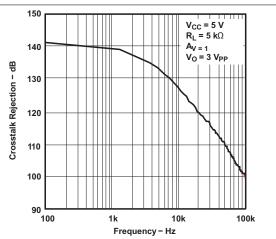
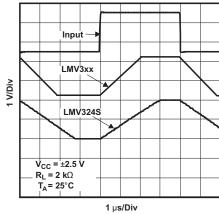


Figure 6-26. Cross-Talk Rejection vs Frequency



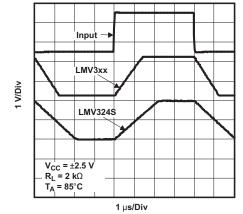
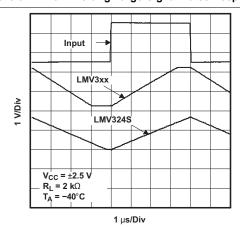


Figure 6-27. Noninverting Large-Signal Pulse Response





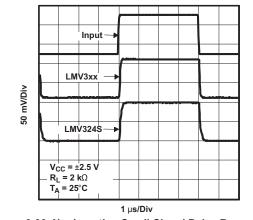


Figure 6-29. Noninverting Large-Signal Pulse Response

Figure 6-30. Noninverting Small-Signal Pulse Response



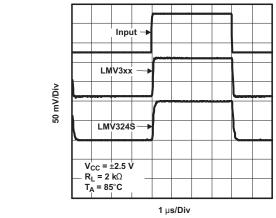


Figure 6-31. Noninverting Small-Signal Pulse Response

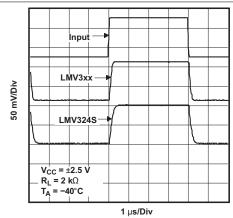


Figure 6-32. Noninverting Small-Signal Pulse Response

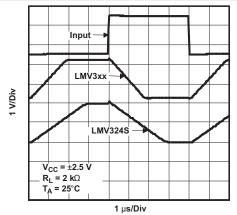


Figure 6-33. Inverting Large-Signal Pulse Response

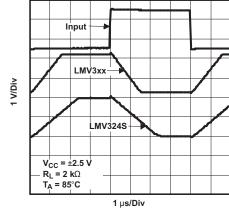


Figure 6-34. Inverting Large-Signal Pulse Response

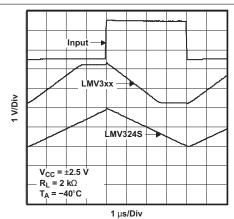


Figure 6-35. Inverting Large-Signal Pulse Response

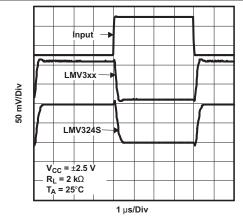
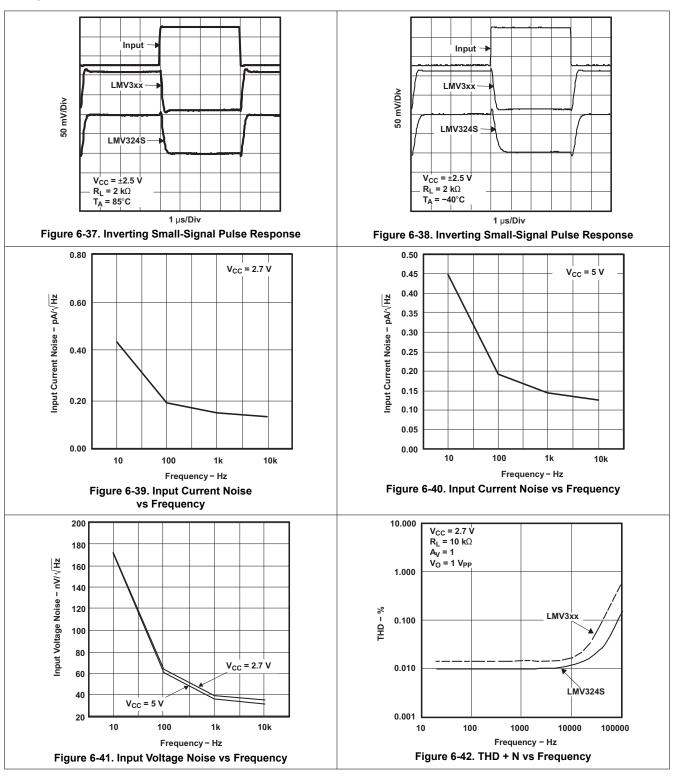
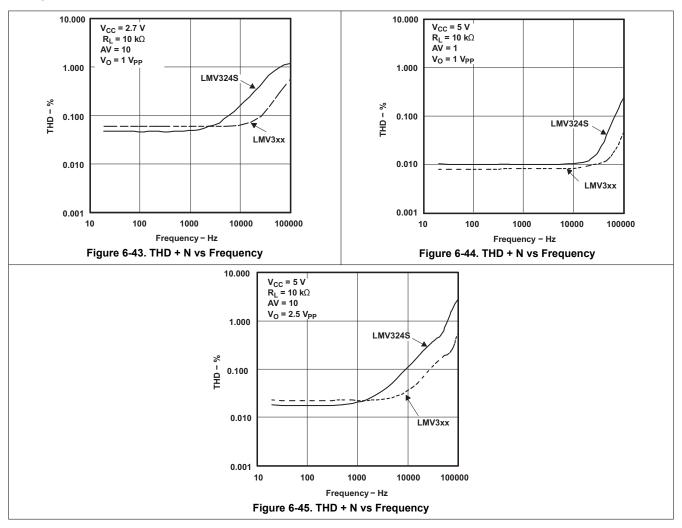


Figure 6-36. Inverting Small-Signal Pulse Response











7 Detailed Description

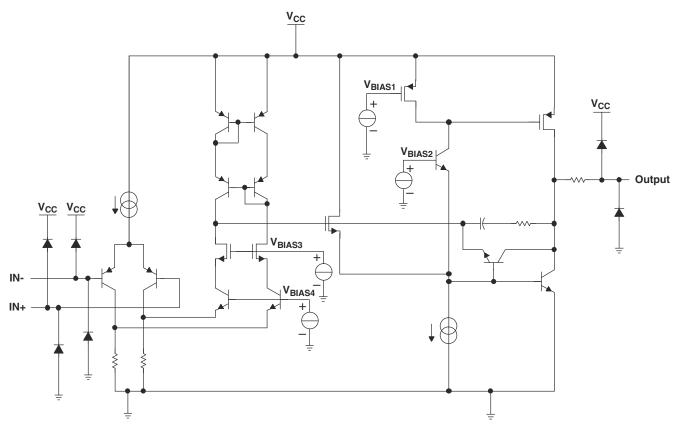
7.1 Overview

The LMV321, LMV358, and LMV324 devices are single, dual, and quad low-voltage (2.7 V to 5.5 V) operational amplifiers with rail-to-rail output swing.

The LMV321, LMV358, and LMV324 devices are the most cost-effective solutions for applications where low-voltage operation, space saving, and low cost are needed. These amplifiers are designed specifically for low-voltage (2.7 V to 5 V) operation, with performance specifications meeting or exceeding the LM358 and LM324 devices that operate from 5 V to 30 V. Additional features of the LMV3xx devices are a common-mode input voltage range that includes ground, 1-MHz unity-gain bandwidth, and 1-V/µs slew rate.

The LMV321 device is available in the ultra-small package, which is approximately one-half the size of the DBV (SOT-23) package. This package saves space on printed circuit boards and enables the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

7.2 Functional Block Diagram





7.3 Feature Description

7.3.1 Operating Voltage

The LMV321, LMV358, and LMV324 devices are fully specified and ensured for operation from 2.7 V to 5 V. In addition, many specifications apply from –40°C to 125°C. Parameters that vary significantly with operating voltages or temperature are shown in the *Typical Characteristics* graphs.

7.3.2 Unity-Gain Bandwidth

The unity-gain bandwidth is the frequency up to which an amplifier with a unity gain may be operated without greatly distorting the signal. The LMV321, LMV358, LMV324 devices have a 1-MHz unity-gain bandwidth.

7.3.3 Slew Rate

The slew rate is the rate at which an operational amplifier can change its output when there is a change on the input. The LMV321, LMV358, LMV324 devices have a 1-V/µs slew rate.

7.4 Device Functional Modes

The LMV321, LMV358, LMV324 devices are powered on when the supply is connected. Each of these devices can be operated as a single supply operational amplifier or dual supply amplifier depending on the application.



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Typical Application

Some applications require differential signals. Figure 8-1 shows a simple circuit to convert a single-ended input of 0.5 to 2 V into differential output of ± 1.5 V on a single 2.7-V supply. The output range is intentionally limited to maximize linearity. The circuit is composed of two amplifiers. One amplifier acts as a buffer and creates a voltage, V_{OUT+} . The second amplifier inverts the input and adds a reference voltage to generate V_{OUT-} . Both V_{OUT+} and V_{OUT-} range from 0.5 to 2 V. The difference, V_{DIFF} , is the difference between V_{OUT+} and V_{OUT-} . The LMV358 was used to build this circuit.

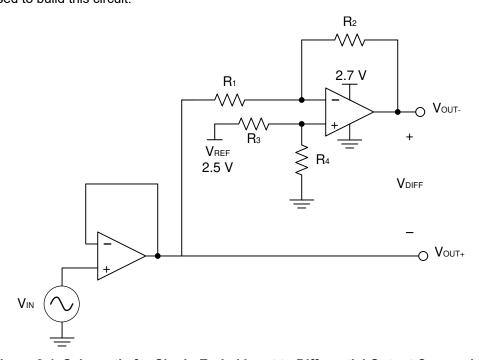


Figure 8-1. Schematic for Single-Ended Input to Differential Output Conversion



8.1.1 Design Requirements

The design requirements are as follows:

Supply voltage: 2.7 VReference voltage: 2.5 V

Input: 0.5 to 2 V

Output differential: ±1.5 V

8.1.2 Detailed Design Procedure

The circuit in Figure 8-1 takes a single-ended input signal, V_{IN} , and generates two output signals, V_{OUT+} and V_{OUT-} using two amplifiers and a reference voltage, V_{REF} . V_{OUT+} is the output of the first amplifier and is a buffered version of the input signal, V_{IN} (see Equation 1). V_{OUT-} is the output of the second amplifier which uses V_{REF} to add an offset voltage to V_{IN} and feedback to add inverting gain. The transfer function for V_{OUT-} is Equation 2.

$$V_{OUT+} = V_{IN} \tag{1}$$

$$V_{OUT-} = V_{REF} \times \left(\frac{R_4}{R_3 + R_4}\right) \times \left(1 + \frac{R_2}{R_1}\right) - V_{IN} \times \frac{R_2}{R_1}$$
(2)

The differential output signal, V_{DIFF} , is the difference between the two single-ended output signals, V_{OUT+} and V_{OUT-} . Equation 3 shows the transfer function for V_{DIFF} . By applying the conditions that $R_1 = R_2$ and $R_3 = R_4$, the transfer function is simplified into Equation 6. Using this configuration, the maximum input signal is equal to the reference voltage and the maximum output of each amplifier is equal to the V_{REF} . The differential output range is $2 \times V_{REF}$. Furthermore, the common mode voltage will be one half of V_{REF} (see Equation 7).

$$V_{DIFF} = V_{OUT+} - V_{OUT-} = V_{IN} \times \left(1 + \frac{R_2}{R_1}\right) - V_{REF} \times \left(\frac{R_4}{R_3 + R_4}\right) \left(1 + \frac{R_2}{R_1}\right)$$
(3)

$$V_{OUT+} = V_{IN} \tag{4}$$

$$V_{OUT-} = V_{REF} - V_{IN}$$
 (5)

$$V_{DIFF} = 2 \times V_{IN} - V_{REF} \tag{6}$$

$$V_{cm} = \left(\frac{V_{OUT+} + V_{OUT-}}{2}\right) = \frac{1}{2}V_{REF}$$
(7)

8.1.2.1 Amplifier Selection

Linearity over the input range is key for good dc accuracy. The common mode input range and the output swing limitations determine the linearity. In general, an amplifier with rail-to-rail input and output swing is required. Bandwidth is a key concern for this design. Because LMV358 has a bandwidth of 1 MHz, this circuit will only be able to process signals with frequencies of less than 1 MHz.

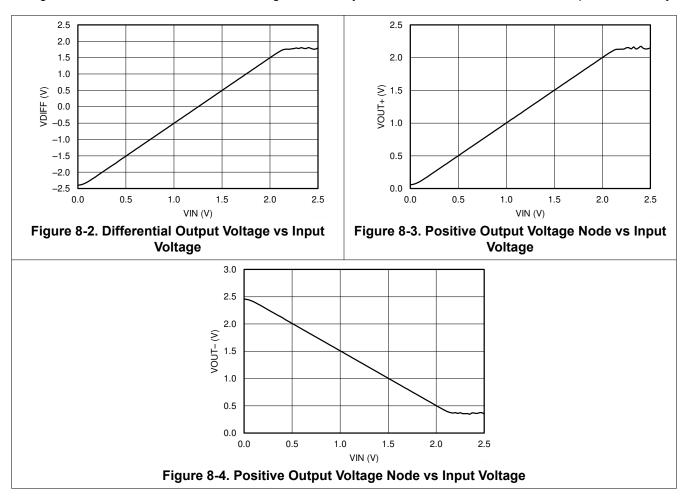
8.1.2.2 Passive Component Selection

Because the transfer function of V_{OUT-} is heavily reliant on resistors (R_1 , R_2 , R_3 , and R_4), use resistors with low tolerances to maximize performance and minimize error. This design used resistors with resistance values of 36 k Ω with tolerances measured to be within 2%. If the noise of the system is a key parameter, the user can select smaller resistance values (6 k Ω or lower) to keep the overall system noise low. This ensures that the noise from the resistors is lower than the amplifier noise.



8.1.3 Application Curves

The measured transfer functions in Figure 8-2, Figure 8-3, and Figure 8-4 were generated by sweeping the input voltage from 0 V to 2.5 V. However, this design should only be used between 0.5 V and 2 V for optimum linearity.



8.2 Power Supply Recommendations

The LMV321, LMV358, LMV324 devices are specified for operation from 2.7 to 5 V; many specifications apply from –40°C to 125°C. The *Typical Characteristics* section presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

CAUTION

Supply voltages larger than 5.5 V can permanently damage the device (see the *Absolute Maximum Ratings*).

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies. For more detailed information on bypass capacitor placement, refer to the *Layout section*.



8.3 Layout

8.3.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the
 operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low impedance
 power sources local to the analog circuitry.
 - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective
 methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes.
 A ground plane helps distribute heat and reduces EMI noise pickup. Ensure to physically separate digital and
 analog grounds, paying attention to the flow of the ground current. For more detailed information, refer to
 Circuit Board Layout Techniques.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it
 is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed
 to in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting
 input minimizes parasitic capacitance, as shown in Layout Example.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

8.3.2 Layout Example

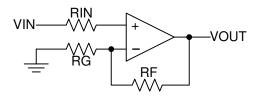


Figure 8-5. Operational Amplifier Schematic for Noninverting Configuration

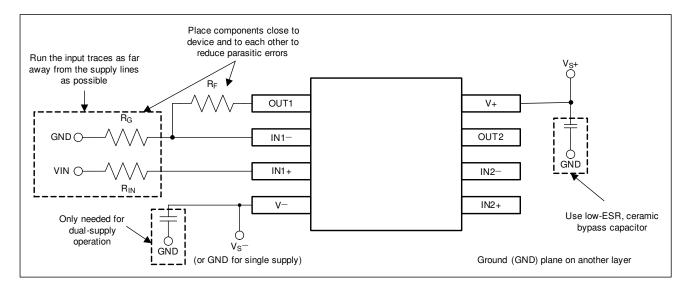


Figure 8-6. Operational Amplifier Board Layout for Noninverting Configuration



9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.





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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMV321IDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RC1F	Samples
LMV321IDBVRE4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RC1F	Samples
LMV321IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RC1F	Samples
LMV321IDBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RC1F	Samples
LMV321IDCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(R3F, R3K, R3O, R3 R, R3Z)	Samples
LMV321IDCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	(R3F, R3K, R3O, R3 R, R3Z)	Samples
LMV321IDCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU SN NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(R3C, R3F, R3R)	Samples
LMV324ID	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324I	
LMV324IDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	LMV324I	Samples
LMV324IDRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324I	Samples
LMV324IDRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324I	Samples
LMV324IPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	MV324I	Samples
LMV324IPWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV324I	Samples
LMV324IPWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV324I	Samples
LMV324QD	LIFEBUY	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324Q	
LMV324QDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324Q	Samples
LMV324QDRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LMV324Q	Samples
LMV324QPW	LIFEBUY	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV324Q	
LMV324QPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	MV324Q	Samples
LMV324QPWRE4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 125	MV324Q	Samples
LMV358ID	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMV358IDDUR	LIFEBUY	VSSOP	DDU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RA5R	
LMV358IDDURG4	NRND	VSSOP	DDU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RA5R	
LMV358IDG4	NRND	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	
LMV358IDGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(R5B, R5Q, R5R)	Samples
LMV358IDGKRG4	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(R5B, R5Q, R5R)	Samples
LMV358IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IDRE4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IDRG4	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358IPW	LIFEBUY	TSSOP	PW	8	150	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	
LMV358IPWG4	NRND	TSSOP	PW	8	150	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	
LMV358IPWR	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	MV358I	Samples
LMV358IPWRG4	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358I	Samples
LMV358QD	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358Q	
LMV358QDDUR	LIFEBUY	VSSOP	DDU	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	RAHR	
LMV358QDG4	LIFEBUY	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358Q	
LMV358QDGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(RHO, RHR)	Samples
LMV358QDGKRG4	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	(RHO, RHR)	Samples
LMV358QDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	MV358Q	Samples
LMV358QPWR	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU SN	Level-2-260C-1 YEAR	-40 to 125	MV358Q	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

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(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV321IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321IDBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
LMV321IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV321IDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV321IDCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV321IDCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV324IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324IDR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
LMV324IDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324IDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV324IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV324IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV324IPWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV324QDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
LMV324QPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV324QPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
LMV358IDDUR	VSSOP	DDU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
LMV358IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
LMV358IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358IDR	SOIC	D	8	2500	330.0	12.8	6.4	5.2	2.1	8.0	12.0	Q1
LMV358IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV358IDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV358IPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LMV358IPWRG4	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
LMV358QDDUR	VSSOP	DDU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
LMV358QDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
LMV358QDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358QDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV358QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
LMV358QPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV321IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV321IDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
LMV321IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
LMV321IDCKR	SC70	DCK	5	3000	190.0	190.0	30.0
LMV321IDCKT	SC70	DCK	5	250	190.0	190.0	30.0
LMV321IDCKT	SC70	DCK	5	250	180.0	180.0	18.0
LMV324IDR	SOIC	D	14	2500	340.5	336.1	32.0
LMV324IDR	SOIC	D	14	2500	364.0	364.0	27.0
LMV324IDRG4	SOIC	D	14	2500	356.0	356.0	35.0
LMV324IDRG4	SOIC	D	14	2500	340.5	336.1	32.0
LMV324IPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
LMV324IPWR	TSSOP	PW	14	2000	366.0	364.0	50.0
LMV324IPWR	TSSOP	PW	14	2000	364.0	364.0	27.0
LMV324IPWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
LMV324QDR	SOIC	D	14	2500	356.0	356.0	35.0
LMV324QPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
LMV324QPWR	TSSOP	PW	14	2000	366.0	364.0	50.0
LMV358IDDUR	VSSOP	DDU	8	3000	202.0	201.0	28.0



PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV358IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
LMV358IDGKR	VSSOP	DGK	8	2500	370.0	355.0	55.0
LMV358IDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
LMV358IDR	SOIC	D	8	2500	364.0	364.0	27.0
LMV358IDR	SOIC	D	8	2500	340.5	336.1	25.0
LMV358IDRG4	SOIC	D	8	2500	340.5	336.1	25.0
LMV358IPWR	TSSOP	PW	8	2000	366.0	364.0	50.0
LMV358IPWRG4	TSSOP	PW	8	2000	356.0	356.0	35.0
LMV358QDDUR	VSSOP	DDU	8	3000	202.0	201.0	28.0
LMV358QDGKR	VSSOP	DGK	8	2500	370.0	355.0	55.0
LMV358QDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
LMV358QDGKR	VSSOP	DGK	8	2500	366.0	364.0	50.0
LMV358QDR	SOIC	D	8	2500	340.5	336.1	25.0
LMV358QPWR	TSSOP	PW	8	2000	366.0	364.0	50.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

an annensions are norminal								
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LMV324ID	D	SOIC	14	50	506.6	8	3940	4.32
LMV324QD	D	SOIC	14	50	506.6	8	3940	4.32
LMV324QPW	PW	TSSOP	14	90	530	10.2	3600	3.5
LMV358ID	D	SOIC	8	75	507	8	3940	4.32
LMV358ID	D	SOIC	8	75	506.6	8	3940	4.32
LMV358IDG4	D	SOIC	8	75	507	8	3940	4.32
LMV358IDG4	D	SOIC	8	75	506.6	8	3940	4.32
LMV358IPW	PW	TSSOP	8	150	530	10.2	3600	3.5
LMV358IPWG4	PW	TSSOP	8	150	530	10.2	3600	3.5
LMV358QD	D	SOIC	8	75	507	8	3940	4.32
LMV358QDG4	D	SOIC	8	75	507	8	3940	4.32

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE TRANSISTOR



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.





NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





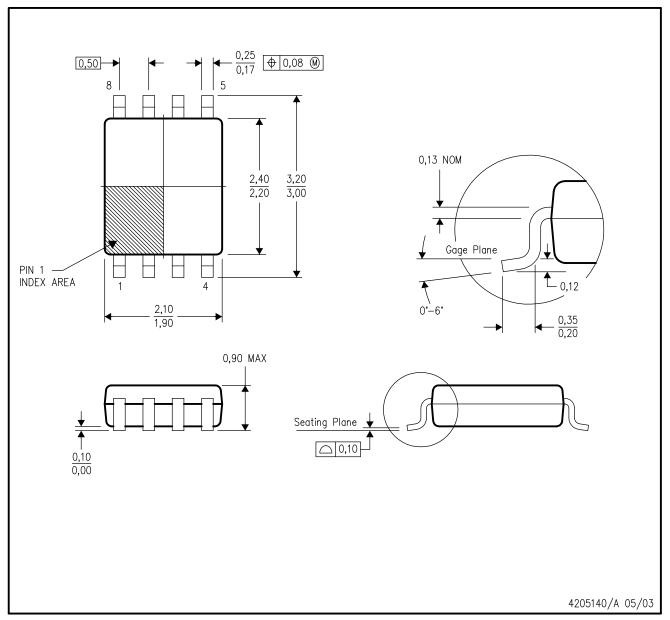
NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



DDU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

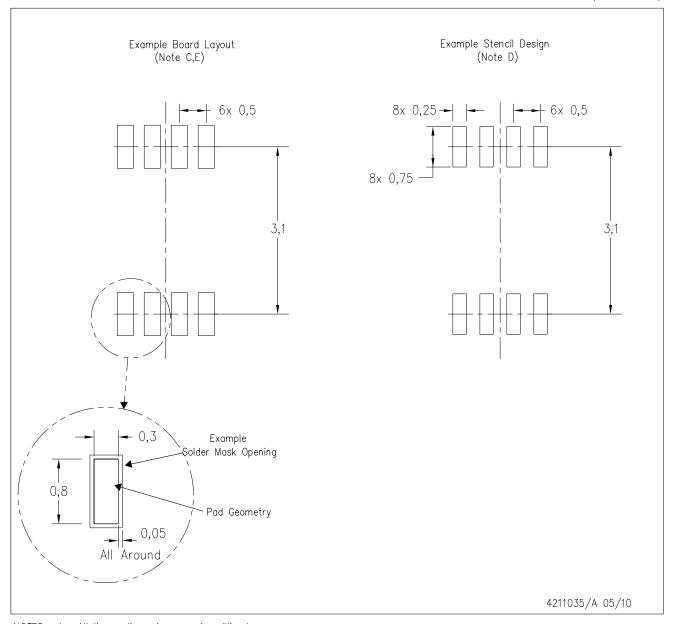


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation CA.



DDU (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE (DIE UP)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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